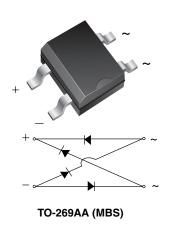


Vishay General Semiconductor

Miniature Glass Passivated Fast Recovery Surface Mount Bridge Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	0.5 A			
V _{RRM}	200 V, 400 V			
I _{FSM}	30 A			
t _{rr}	150 ns			
V_{F}	1.25 V			
T _J max.	150 °C			

FEATURES





- · Saves space on printed circuit boards
- · Ideal for automated placement
- (e3)
- Fast recovery, low switching loss

ROHS

- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

General purpose use in ac-to-dc bridge full wave rectification for power supply, lighting ballaster, battery charger, home appliances, office equipment, and telecommunication applications.

MECHANICAL DATA

Case: TO-269AA (MBS)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for commercial grade, meets JESD 201 class

1A whisker test

Polarity: As marked on body

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	RMB2S	RMB4S	UNIT	
Device marking code		2R	4R		
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	V	
Maximum RMS voltage	V _{RMS}	140	280	V	
Maximum DC blocking voltage	V_{DC}	200	400	V	
Maximum average forward output on glass-epoxy P.C.B. rectified current at $T_A = 30 ^{\circ}\text{C}$ on aluminum substrate	I _{F(AV)}	0.5 ⁽¹⁾ 0.8 ⁽²⁾		А	
Peak forward surge current 8.3 msec single half sine-wave superimposed on rated load	I _{FSM}	30		А	
Rating for fusing (t < 8.3 ms)	I ² t	5.0			
Operating junction and storage temperature range	T_J , T_{STG}	- 55 to + 150 °		°C	

Notes:

- (1) On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3 mm) pads
- (2) On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20 mm) mounted on 0.05 x 0.05" (1.3 x 1.3 mm) solder pad

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	RMB2S	RMB4S	UNIT
Maximum instantaneous forward voltage drop per diode	0.4 A		V _F	1.25		V
Maximum DC reverse current at rated DC blocking voltage per diode		T _A = 25 °C T _A = 125 °C	I _R	5.0 100		μΑ
Maximum reverse recovery time per diode	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$		t _{rr}	150		ns
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	13		pF

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	RMB2S	RMB4S	UNIT	
Typical thermal resistance	R _{θJA} R _{θJA} R _{θJL}	85 ⁽¹⁾ 70 ⁽²⁾ 20 ⁽¹⁾		°C/W	

Notes:

- (1) On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3 mm) pads
- (2) On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20 mm) mounted on 0.05 x 0.05" (1.3 x 1.3 mm) solder pad

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
RMB4S-E3/45	0.22	45	100	Tube	
RMB4S-E3/80	0.22	80	3000	13" diameter paper tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

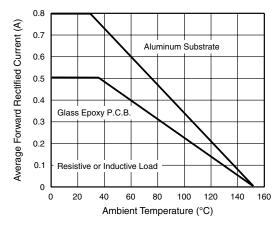


Figure 1. Maximum Forward Current Derating Curve

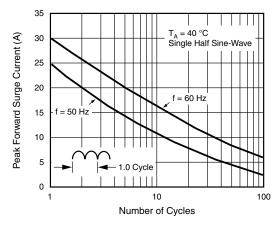


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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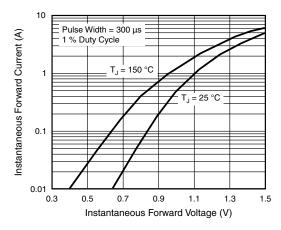


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

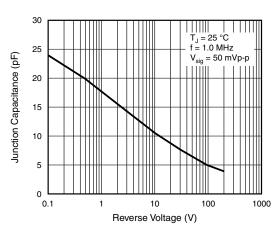


Figure 5. Typical Junction Capacitance Per Diode

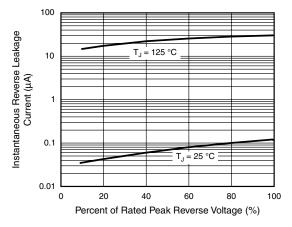
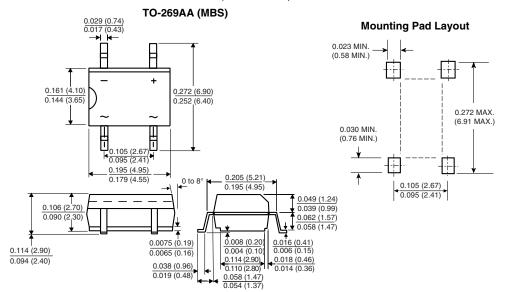


Figure 4. Typical Reverse Leakage Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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